APPLICATION FOR NEW COURSE

1.	Submitted by College of Engineering	Date 11/22/05
	Department/Division offering course Electrical and Compute	er Engineering
2.	Proposed designation and Bulletin description of this course	
	a. Prefix and Number EE 570 b. Title *NOTE: If the title is longer than 24 characters (A sensible title (not exceeding 24 characters) for	
	c. Lecture/Discussion hours per week 3	d. Laboratory hours per week
	e. Studio hours per week	f. Credits 3
	g. Course description	
	Energy bands in crystals; heter	ostructures; quantum wells and low
	h. Prerequisites (if any) in nanostructures: EE 360 and engineering standing	imensional electrongus and MODFET; transmissions, current topics in nanoscale devices. , or consent of instructor.
4.	i. May be repeated to a maximum of MSE To be cross-listed as ME/GME S70 Prefix and Number	(if applicable) On Signature, Chairman, cross-listing department
5.	Effective Date Spring 2008: -2010	Signature, Chairman, cross-listing department 1 pproduct by ME (each f) 2-/22/06 (semester and year)
6.	Course to be offered Fall Spi	oring Summer
7.	Will the course be offered each year? (Explain if not annually)	☐ Yes ☐ No
8.	Why is this course needed? This course is needed because the electronics industry and	d the engineering nanoelectronics industry needs
	graduates with knowledge taught in this course.	
9.	a. By whom will the course be taught? Dr. Vijay Singh	
	b. Are facilities for teaching the course now available? If not, what plans have been made for providing them?	Yes No

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10.	What enrollment may be reasonably anticipated?	
11.	Will this course serve students in the Department primarily?	⊌ Yes □ No
	Will it be of service to a significant number of students outside the Department? If so, explain.	□/Yes □ No
	Will the course serve as a University Studies Program course? If yes, under what Area?	☐ Yes ☑ No
12.	Check the category most applicable to this course	
	traditional; offered in corresponding departments elsewhere;	
	relatively new, now being widely established not yet to be found in many (or any) other universities	
13.	Is this course applicable to the requirements for at least one degree or certificate at the University of Kentucky?	✓ Yes ☐ No
14.	Is this course part of a proposed new program: If yes, which?	Yes No
15.	Will adding this course change the degree requirements in one or more programs?* If yes, explain the change(s) below	Yes 🗹 No
16.	Attach a list of the major teaching objectives of the proposed course and outline and/or reference	list to be used
17.	If the course is a 100-200 level course, please submit evidence (e.g., correspondence) that the Corbeen consulted.	
18.	If the course is 400G or 500 level, include syllabi or course statement showing differentiation for students in assignments, grading criteria, and grading scales.	undergraduate and graduate
19.	Within the Department, who should be contacted for further information about the proposed cours	se?
	Name Dr. Vijay Singh Phone Extensi	on 257-3243

^{*}NOTE: Approval of this course will constitute approval of the program change unless other program modifications are proposed.

APPLICATION FOR NEW COURSE

Signatures of Approval:	
N. Cin	11/22/05
Department Chair / 21-0 un Favor	Date
Enhant Daniel	12-01-09
Dean of the College	Date
	1-20-09
	Date of Notice to the Faculty
$\mathcal{O}(\mathcal{O})$	4/28/2010
*Undergraduate Council	/ Date
*University Studies	Date
*Graduate Council	· Date
*Academic Council for the Medical Center	Date
*Senste Council (Chair)	Date of Notice to University Senate
*If applicable, as provided by the Rules of the University Senate	
	NOON NOON NOON NOON NOON NOON NOON NOO
ACTION OTHER THAN APPROVAL	

SYLLABUS

EE 570- Fundamentals of Nanoelectronic Devices and Materials

Department of Electrical and Computer Engineering, University of Kentucky

Instructor: Dr. Vijay P. Singh

Office: 467 D Anderson Hall

E-mail: vsingh@engr.uky.edu

Web: http://www.engr.uky.edu/~vsingh

EE570 URL:

Office hours:

Meeting Time and Place:

Textbook: "The Physics of Low-Dimensional Semiconductors", J. H. Davies Cambridge University Press, 1998, ISBN 0-521-48148-1, QC611.8.L68039

Grading Policy:

Grade for the <u>undergraduate students</u> will be based on:

Homework Assignments	15%
Quizzes Final Exam	40%
Final Exam	15%
Project I	30%

Grade for the graduate students will be based on:

Homework Assignments	15%
Quizzes	40%
Final Exam	15%
Project I	15%
Project II (Advanced Project)	15%

• Homework will be assigned almost every week. For full credit, problem solutions must show a clear systemic method for arriving at the correct solution. Points will be taken off for incorrect solutions or work that is difficult to follow.

- Failure to take an exam during the assigned class period will result in a grade of zero for that test. In such a case, student should see the instructor to explain the circumstances.
- The student is responsible for all business conducted during any scheduled class period. Any revision to the test dates, homework assignments, etc. will be announced during the class period.
- The detected use of unethical tactics on a quiz, test, or homework will result in an E for the course. This includes copying another person's work, or making your work available for others to copy. Appropriate actions will be taken in accordance with the university policies on cheating and plagiarism.
- The student is expected to read the text and is responsible for all material in the reading assignments. The sections of the text should be read prior to the class meetings covering the material.

Course Topics

- I. <u>Foundations:</u> Wave mechanics and the Schrodinger Equation; Free Particles; Bound Particles; Charge and current densities.
- II. Energy Bands in Crystalline Materials:

Band Structure in One Dimension; Electron Motion; Density of States; Band Structure; Crystal Structure and Band Structure in common Semiconductors; Measurement of Band Gap.

- III. <u>Heterostructures:</u> General properties of heterostructures; Growth of heterostructures; Band engineering; Quantum wells, Superlattices and Silicon-Germanium heterostructures; Quantum dots and wires; Optical confinement
- IV. Quantum Wells and Low Dimensional Systems: Infinitely deep potential well; Square Well of Finite Depth; Two and Three Dimensional Potential Wells.
- V. <u>The Two- Dimensional Electron Gas and MODFET</u>: Band Diagram of MODFET; Current-Voltage Characteristics and Threshold Voltage in MODFET
- VI. <u>Transmission in nanostructures</u>: Tunneling; Tunneling in heterostructures; Transmission matrices (T- matrices); Resonant tunneling; Tunneling transport; Current and conductance in one dimension; Current in two and three dimensions; Quantized conductance in nanostructures.
- VII. <u>Current Topics in Nanoscale Devices</u>: Solar cells, display devices, sensors and other devices of interest.

Student Learning Outcomes

Upon completion of the course, the student will have:

- The basic understanding of the behaviour of electrons in semiconductor crystals, Schrodinger equation; energy levels and bands and charge and current densities
- 2. The basic understanding of heterostructures; band engineering; quantum wells, superlattices and quantum dots and wires.
- 3. The basic understanding of electron transport in nanostructures, tunneling; resonant tunneling and quantized conductance in nanostructures.

Homework policy: Homework will generally be assigned each week. The homework assignments will be distributed in the Class and/or Web. The homework is to be turned in at the *beginning* of the class period. No late homework will be accepted.

Attendance: If a student is to be absent from class for an extended period of time (two classes or more), the Instructor must be notified in advance, if possible, or by the second class of the absence.

Final Exam: Any student having a legal conflict on that exam day will need to notify the instructor *no later* than the last week of classes. Anyone failing to notify the instructor before this time will have to take the exam during the scheduled time.

Grading Assignment will be based on your final score for the course based on the homework, midterm exams, project and final exam, as outlined above. The letter grade assignment will then be calculated according to the table below.

(a) For Undergraduate Students:

Final Grade/Composite Score	Letter Grade
86-100 %	A
46-85%	B,C,D
Below 45%	E

(b) For Graduate Students:

Final Grade/Composite Score	Letter Grade
86-100 %	Α
55-85%	В,С
Below 55%	Е